

CMOS 8-Stage Presettable Synchronous Down Counters

High-Voltage Types (20-Volt Rating)

CD40102B – 2-Decade BCD Type
CD40103B – 8-Bit Binary Type

The RCA-CD40102B, and CD40103B consist of an 8-stage synchronous down counter with a single output which is active when the internal count is zero. The CD40102B is configured as two cascaded 4-bit BCD counters, and the CD40103B contains a single 8-bit binary counter. Each type has control inputs for enabling or disabling the clock, for clearing the counter to its maximum count, and for presetting the counter either synchronously or asynchronously. All control inputs and the CARRY-OUT/ZERO-DETECT output are active-low logic.

In normal operation, the counter is decremented by one count on each positive transition of the CLOCK. Counting is inhibited when the CARRY-IN/COUNTER ENABLE (CI/CE) input is high. The CARRY-OUT/ZERO-DETECT (CO/ZD) output goes low when the count reaches zero if the CI/CE input is low, and remains low for one full clock period.

When the SYNCHRONOUS PRESET-ENABLE (SPE) input is low, data at the JAM input is clocked into the counter on the next positive clock transition regardless of the state of the CI/CE input. When the ASYNCHRONOUS PRESET-ENABLE (APE) input is low, data at the JAM inputs is asynchronously forced into the counter regardless of the state of the SPE, CI/CE, or CLOCK inputs. JAM inputs JO-J7 represent two 4-bit BCD words for the CD40102B and a single 8-bit binary word for the CD40103B.

When the CLEAR (CLR) input is low, the counter is asynchronously cleared to its maximum count (9910 for the CD40102B and 25510 for the CD40103B) regardless of the state of any other input. The precedence relationship between control inputs is indicated in the truth table.

If all control inputs except CI/CE are high at the time of zero count, the counters will jump to the maximum count, giving a counting sequence of 100 or 256 clock pulses long.

The CD40102B and CD40103B may be cascaded using the CI/CE input and the CO/ZD output, in either a synchronous or ripple mode as shown in Figs.21 and 22.

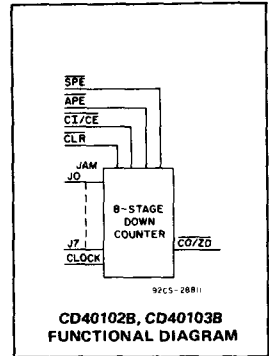
The CD40102B and CD40103B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead ceramic flat packages (K suffix), and in chip form (H suffix).

Features:

- Synchronous or asynchronous preset
- Medium-speed operation: $f_{CL} = 3.6 \text{ MHz (typ.) @ } V_{DD} = 10 \text{ V}$
- Cascadable
- 100% tested for quiescent current at 20 V
- Maximum input current of $1 \mu\text{A}$ at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = $1 \text{ V at } V_{DD} = 5 \text{ V}$
 $2 \text{ V at } V_{DD} = 10 \text{ V}$
 $2.5 \text{ V at } V_{DD} = 15 \text{ V}$
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No.13A, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Divide-by-"N" counters
- Programmable timers
- Interrupt timers
- Cycle/program counter



RECOMMENDED OPERATING CONDITIONS AT $T_A = 25^\circ\text{C}$, Unless Otherwise Specified
For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

Characteristic	VDD	LIMITS		Units
		Min.	Max.	
Supply Voltage Range (At $T_A =$ Full Package-Temperature Range)		3	18	V
Clock Pulse Width, t_{W}	5	300	—	ns
	10	180	—	
	15	80	—	
Clear Pulse Width, t_{W}	5	320	—	ns
	10	160	—	
	15	100	—	
APE Pulse Width, t_{W}	5	360	—	ns
	10	160	—	
	15	120	—	
Clock Input Frequency, f_{CL}	5	—	0.7	MHz
	10	—	1.8	
	15	—	2.4	
Clock Rise and Fall Time, $t_{r,CL}$, $t_{f,CL}$	5	—	—	μs
	10	—	15	
	15	—	—	
SPE Setup Time, t_{SU}	5	280	—	ns
	10	140	—	
	15	100	—	
Jam Setup Time, t_{SU}	5	200	—	ns
	10	80	—	
	15	60	—	
CI/CE Setup Time, t_{SU}	5	500	—	ns
	10	250	—	
	15	150	—	

CD40102B, CD40103B Types

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V _{DD}) (Voltages referenced to V _{SS} Terminal)	-0.5 to +20 V
INPUT VOLTAGE RANGE, ALL INPUTS	-0.5 to V _{DD} +0.5 V
DC INPUT CURRENT, ANY ONE INPUT	±10 mA
POWER DISSIPATION PER PACKAGE (P _D):	
For T _A = -40 to +60°C (PACKAGE TYPE E)	500 mW
For T _A = +60 to +85°C (PACKAGE TYPE E)	Derate Linearly at 12 mW/°C to 200 mW
For T _A = -55 to +100°C (PACKAGE TYPES D, F, K)	500 mW
For T _A = +100 to +125°C (PACKAGE TYPES D, F, K)	Derate Linearly at 12 mW/°C to 200 mW
POWER DISSIPATION PER OUTPUT TRANSISTOR	
For T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100 mW
OPERATING-TEMPERATURE RANGE (T _A):	
PACKAGE TYPES D, F, K, H	-55 to +125°C
PACKAGE TYPE E	-40 to +85°C
STORAGE TEMPERATURE RANGE (T _{stg})	-65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 s max.	+265°C

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER- ISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	Values at -55, +25, +125 Apply to D, F, K, H Packages Values at -40, +25, +85 Apply to E Package				+25			
				-55	-40	+85	+125	Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	-	0.5	5	5	5	150	150	-	0.04	5	μA
	-	0.10	10	10	10	300	300	-	0.04	10	
	-	0.15	15	20	20	600	600	-	0.04	20	
	-	0.20	20	100	100	3000	3000	-	0.08	100	
Output Low (Sink) Current I _{OL} Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	-	mA
	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8	-	
Output High (Source) Current, I _{OH} Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0.15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage: Low-Level, V _{OL} Max.	-	0.5	5	0.05				-	0	0.05	V
	-	0.10	10	0.05				-	0	0.05	
	-	0.15	15	0.05				-	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	-	0.5	5	4.95				4.95	5	-	V
	-	0.10	10	9.95				9.95	10	-	
	-	0.15	15	14.95				14.95	15	-	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	-	5	1.5				-	-	1.5	V
	1, 9	-	10	3				-	-	3	
	1.5, 13.5	-	15	4				-	-	4	
Input High Voltage, V _{IH} Min.	0.5, 4.5	-	5	3.5				3.5	-	-	V
	1, 9	-	10	7				7	-	-	
	1.5, 13.5	-	15	11				11	-	-	
Input Current I _{IN} Max.	-	0.18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA

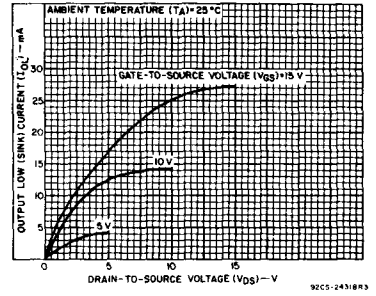


Fig. 1 — Typical output low (sink) current characteristics.

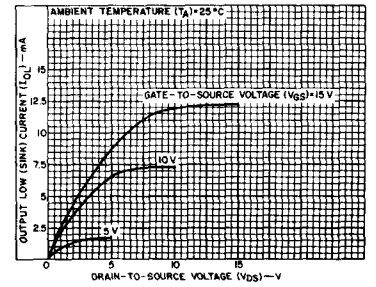


Fig. 2 — Minimum output low (sink) current characteristics.

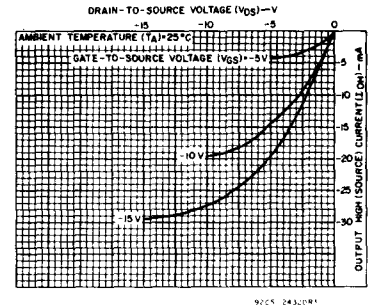


Fig. 3 — Typical output high (source) current characteristics.

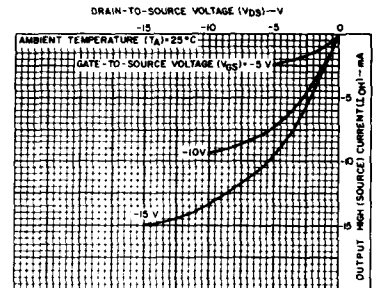


Fig. 4 — Minimum output high (source) current characteristics.

CD40102B, CD40103B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$,
 Input $t_r, t_f = 20\text{ ns}$, $R_L = 200\text{ k}\Omega$

Characteristic	Conditions V_{DD} (V)	Limits All Packages			Units	
		Min.	Typ.	Max.		
Propagation Delay Time (t_{PHL}, t_{PLH}):						
Clock-to-Output (See Fig. 6)	5	—	300	600	ns	
	10	—	130	260		
	15	—	95	190		
Carry In/Counter Enable-to-Output	5	—	200	400		
	10	—	90	180		
	15	—	65	130		
Asynchronous Preset Enable-to-Output	5	—	650	1300		
	10	—	300	600		
	15	—	200	400		
Clear-to-Output	5	—	375	750		
	10	—	180	360		
	15	—	100	200		
Transition Time (t_{THL}, t_{TLH})	5	—	100	200		ns
	10	—	50	100		
	15	—	40	80		
Minimum Clock Pulse Width (t_{CW})	5	—	150	300	ns	
	10	—	90	180		
	15	—	40	80		
Minimum $\overline{\text{CLR}}$ Pulse Width (t_{W})	5	—	160	320		
	10	—	80	160		
	15	—	50	100		
Minimum $\overline{\text{APE}}$ Pulse Width (t_{W})	5	—	180	360		
	10	—	80	160		
	15	—	60	120		
Minimum $\overline{\text{APE}}$ Removal Time (t_{RM})	5	—	110	220		
	10	—	50	100		
	15	—	35	70		
Minimum $\overline{\text{SPE}}$ Set-Up Time (t_{SU})	5	—	140	280		
	10	—	70	140		
	15	—	50	100		
Minimum $\overline{\text{CI}}/\overline{\text{CE}}$ Setup Time (t_{SU})	5	—	250	500		
	10	—	125	250		
	15	—	75	150		
Minimum $\overline{\text{JAM}}$ Set-Up Time (t_{SU}) (Synchronous presetting)	5	—	100	200		
	10	—	40	80		
	15	—	30	60		
Maximum Clock Input Frequency (f_{CL}) (See Fig. 7)	5	0.7	1.4	—	MHz	
	10	1.8	3.6	—		
	15	2.4	4.8	—		
Input Capacitance (C_{IN})			5	7.5	pF	

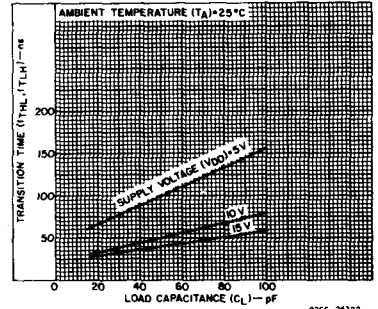


Fig. 5 — Typical transition time as a function of load capacitance.

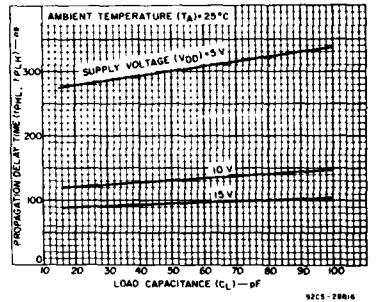


Fig. 6 — Typical propagation delay time as a function of load capacitance (clock to CO/ZD).

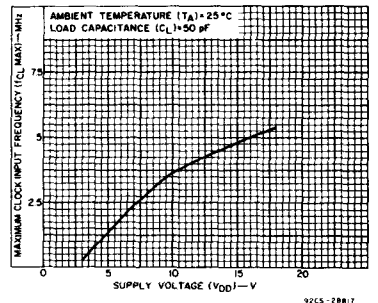


Fig. 7 — Typical maximum clock input frequency as a function of supply voltage.

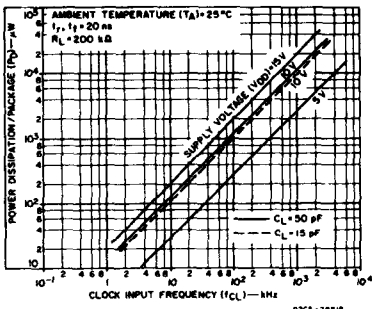


Fig. 8 — Typical dynamic power dissipation as a function of frequency.

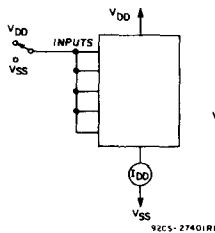


Fig. 9 — Quiescent device current test circuit.

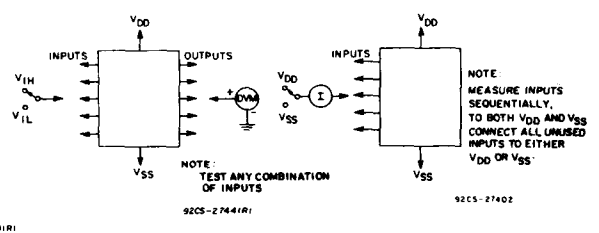


Fig. 10 — Input voltage test circuit.

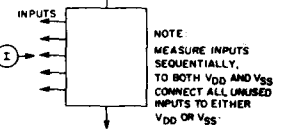


Fig. 11 — Input current test circuit.

CD40102B, CD40103B Types

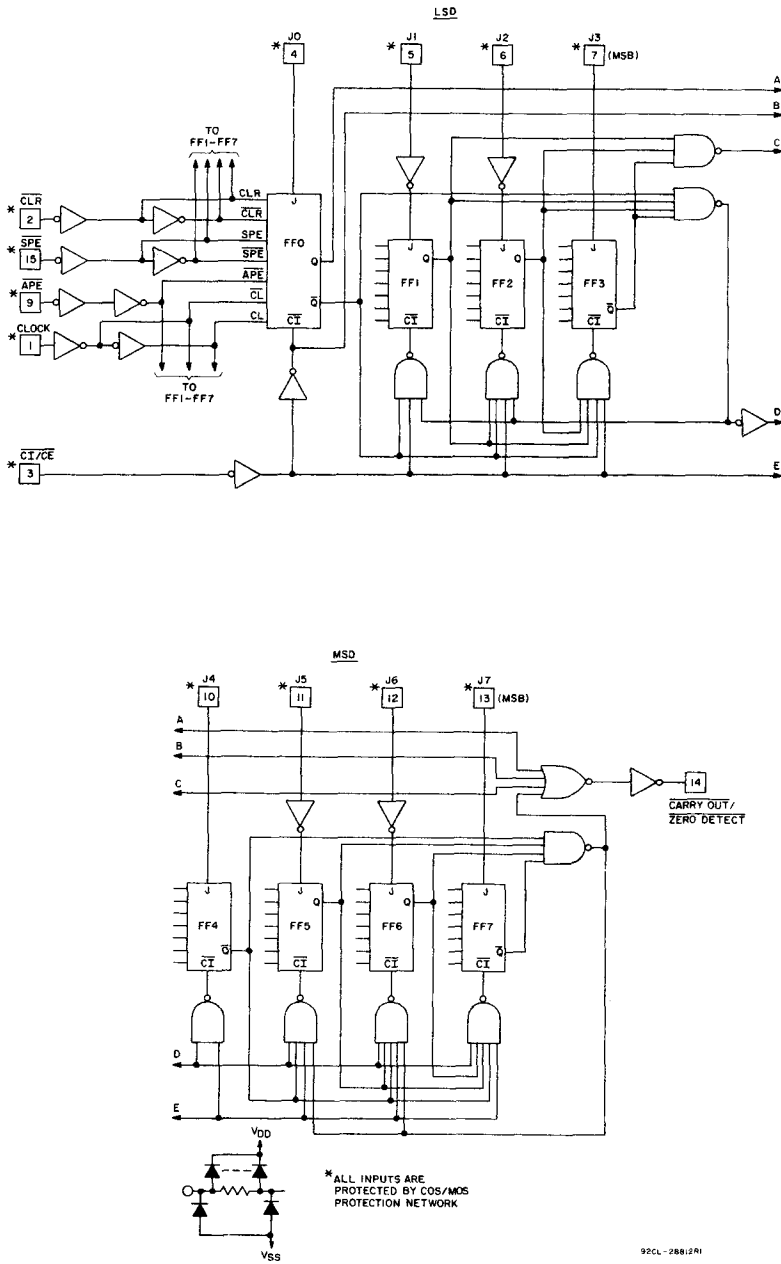


Fig. 12 - Logic diagram for CD40102B.

CD40102B, CD40103B Types

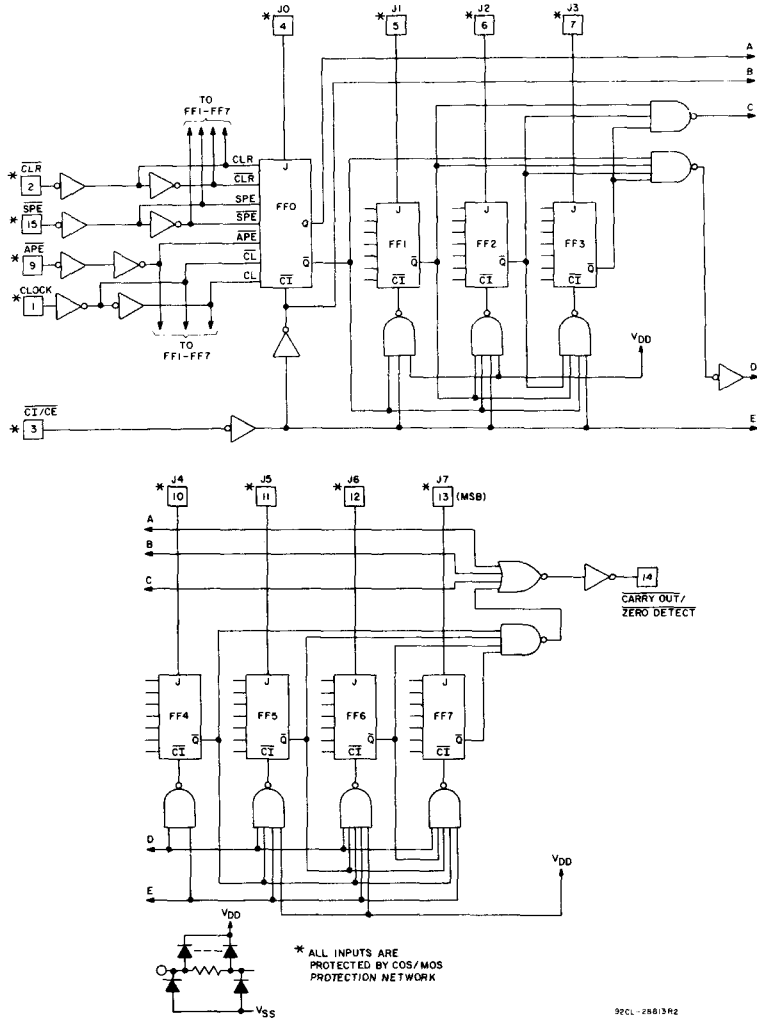


Fig. 13 - Logic diagram for CD40103B.

TRUTH TABLE

CONTROL INPUTS				PRESET MODE	ACTION
CLR	APE	SPE	CI/CE		
1	1	1	1	Synchronous	Inhibit counter
1	1	1	0		Count down
1	1	0	X		Preset on next positive clock transition
1	0	X	X	Asynchronous	Preset asynchronously
0	X	X	X		Clear to maximum count

Notes: 1. 0 = Low level
1 = High level
X = Don't care

- Clock connected to clock input
- Synchronous operation: changes occur on negative-to-positive clock transitions
- JAM inputs: CD40102B BCD: MSD = J7, J6, J5, J4 (J7 is MSB)
LSD = J3, J2, J1, J0 (J3 is MSB)
CD40103B Binary: MSB = J7, LSB = J0

CD40102B, CD40103B Types

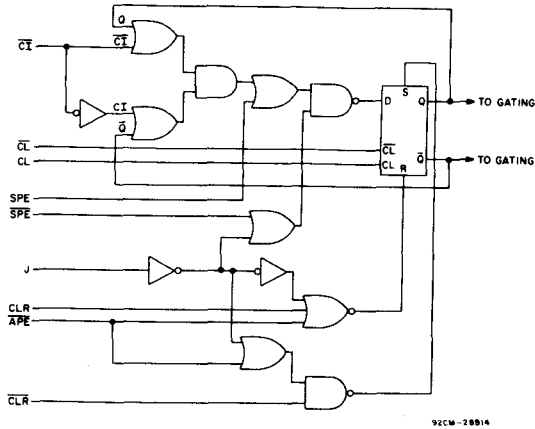


Fig. 14 - Detail logic diagram for flip-flops, FFO - FF7, used in logic diagrams for CD40102B and CD40103B.

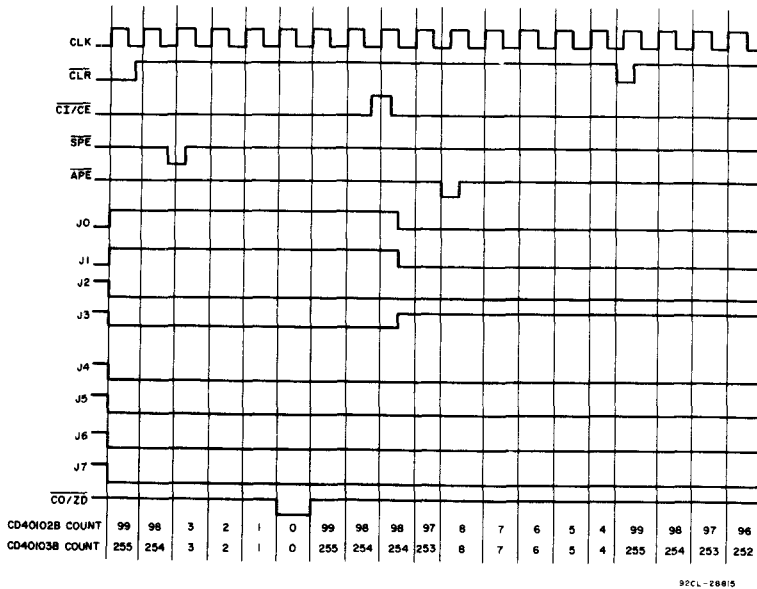
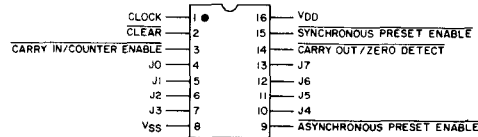


Fig. 15 - Timing diagram for CD40102B and CD40103B.



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CD40102B, CD40103B TERMINAL ASSIGNMENT

CD40102B, CD40103B Types

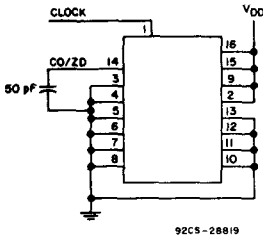


Fig. 16 - Maximum clock frequency test circuit.

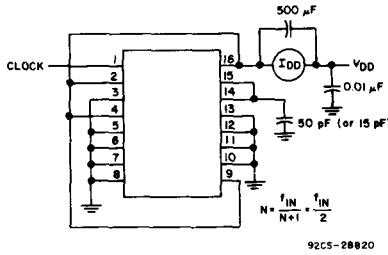


Fig. 17 - Dynamic power dissipation test circuit ($f = 2$ mode).

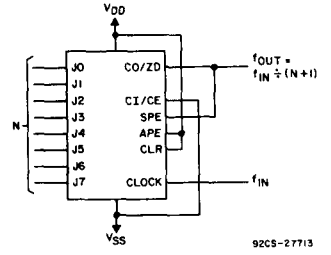


Fig. 18 - Divide-by-"N" counter.

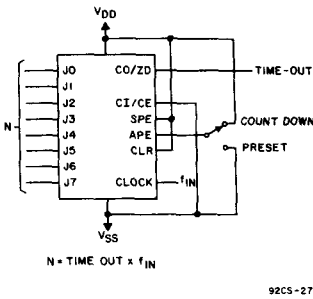


Fig. 19 - Programmable timer.

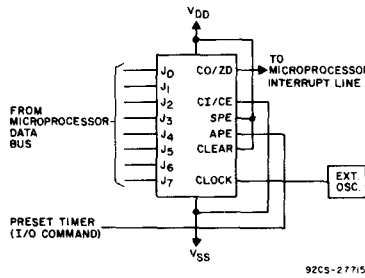
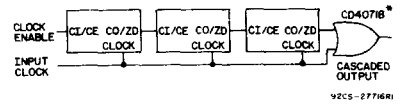


Fig. 20 - Microprocessor interrupt timer.



* An output spike (160 ns @ $V_{DD} = 5$ V) occurs whenever two or more devices are cascaded in the parallel-clocked mode because the clock-to-carry out delay is greater than the carry-in-to-carry out delay. This spike is eliminated by gating the output of the last device with the clock as shown.

Fig. 21 - Synchronous cascading.

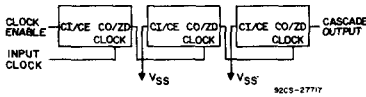
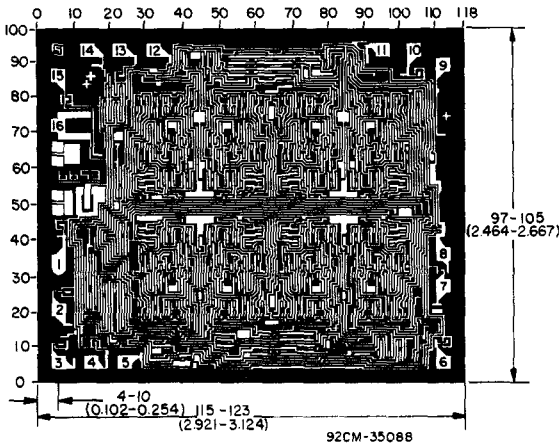


Fig. 22 - Ripple cascading.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions of each CMOS chip represent a chip when it is part of the wafer. When the wafer is separated into individual chips, the angle of cleavage may vary with respect to the chip face for different chips. The actual dimensions of the isolated chip, therefore, may differ slightly from the nominal dimensions shown. The user should consider a tolerance of -3 mils to $+16$ mils applicable to the nominal dimensions shown.

Dimensions and pad layout for CD40102B.



Dimensions and pad layout for CD40103B.

